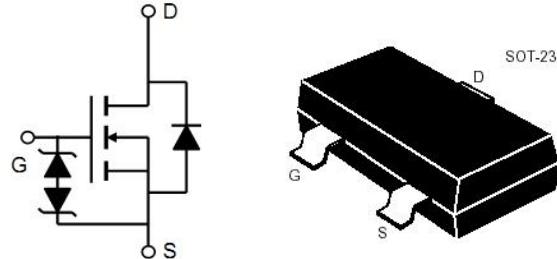


GM2028

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



### N-Channel Enhancement-Mode MOS FET With ESD

N 溝道增強型帶靜電保護 MOS 場效應管

#### ■MAXIMUM RATINGS 最大額定值

Characteristic 特性參數	Symbol 符號	Rat 額定值	Unit 單位
Drain-Source Voltage 漏極-源極電壓	$BV_{DSS}$	20	V
Gate- Source Voltage 柵極-源極電壓	$V_{GS}$	$\pm 6$	V
Drain Current (continuous) 漏極電流-連續	$I_D$	0.3	A
Drain Current (pulsed) 漏極電流-脉沖	$I_{DM}$	0.6	A
Total Device Dissipation 總耗散功率 $T_A=25^\circ\text{C}$ 環境溫度為 $25^\circ\text{C}$	$P_D$	300	mW
Junction 結溫	$T_J$	150	$^\circ\text{C}$
Storage Temperature 儲存溫度	$T_{stg}$	-55 to +150	$^\circ\text{C}$

#### ■DEVICE MARKING 打標

GM2028=W28
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GM2028

## ■ELECTRICAL CHARACTERISTICS 電特性

( $T_A=25^\circ\text{C}$  unless otherwise noted 如無特殊說明，溫度為  $25^\circ\text{C}$ )

Characteristic 特性參數	Symbol 符號	Min 最小值	Typ 典型值	Max 最大值	Unit 單位
Drain-Source Breakdown Voltage 漏極-源極擊穿電壓( $I_D = 250\mu\text{A}, V_{GS}=0\text{V}$ )	$\text{BV}_{DSS}$	20	—	—	V
Gate Threshold Voltage 柵極開啓電壓( $I_D = 250\mu\text{A}, V_{GS} = V_{DS}$ )	$V_{GS(\text{th})}$	0.35	—	1	V
Diode Forward Voltage Drop 內附二極管正向壓降( $I_S=0.3\text{A}, V_{GS}=0\text{V}$ )	$V_{SD}$	—	—	1.1	V
Zero Gate Voltage Drain Current 零柵壓漏極電流( $V_{GS}=0\text{V}, V_{DS}=16\text{V}$ )	$I_{DSS}$	—	—	1	$\mu\text{A}$
Gate Body Leakage 柵極漏電流( $V_{GS}=5\text{V}, V_{DS}=0\text{V}$ )	$I_{GSS}$	—	—	5	$\mu\text{A}$
Static Drain-Source On-State Resistance 静态漏源導通電阻( $I_D=0.3\text{A}, V_{GS}=4.5\text{V}$ )	$R_{DS(\text{ON})}$	—	—	2000	$\text{m}\Omega$
Static Drain-Source On-State Resistance 静态漏源導通電阻( $I_D=0.1\text{A}, V_{GS}=2.5\text{V}$ )	$R_{DS(\text{ON})}$	—	—	3500	$\text{m}\Omega$
Static Drain-Source On-State Resistance 静态漏源導通電阻( $I_D=0.01\text{A}, V_{GS}=1.8\text{V}$ )	$R_{DS(\text{ON})}$	—	—	5000	$\text{m}\Omega$
Input Capacitance 輸入電容 ( $V_{GS}=0\text{V}, V_{DS}=10\text{V}, f=1\text{MHz}$ )	$C_{ISS}$	—	50	—	pF
Output Capacitance 輸出電容 ( $V_{GS}=0\text{V}, V_{DS}=10\text{V}, f=1\text{MHz}$ )	$C_{OSS}$	—	13	—	pF
Turn-ON Time 开啓時間 ( $V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, R_{GEN}=6\Omega$ )	$t_{(\text{on})}$	—	22	—	ns
Turn-OFF Time 短斷時間 ( $V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, R_{GEN}=6\Omega$ )	$t_{(\text{off})}$	—	700	—	ns

Pulse Width  $\leq 300 \mu\text{ s}$ ; Duty Cycle  $\leq 2.0\%$